

Diodes

OFF: $i = 0$ for $V < 0$, $i = 0.7$ for $V > 0$

ON: $i = I_S (e^{V/V_T} - 1)$

Breakdown: V_{BR} , $V_T = \frac{kT}{q} \approx 25\text{mV}$

Verify: $i = I_S e^{V/V_T}$, $V = V_T \ln(i/I_S)$, $V_2 - V_1 = V_T \ln(i_2/i_1)$

for the same current, $-2\text{mV}/^\circ\text{C}$ temp increase

Diodes

half-wave rectifier: $V_S \rightarrow V_O$

peak rectifier: $V_S \rightarrow V_O$

peak detector: $V_S \rightarrow V_O$

Voltage double: clamper + peak detector

diode in small signal: $r_d = \frac{V_T}{I_D}$

PN junction diagram

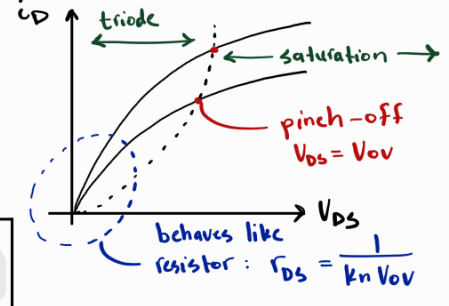
MOSFETs

Structure: S, G, D, P

Equation: $I_D = \frac{1}{2} \mu_n C_{ox} \frac{W}{L} (V_{GS} - V_t)^2$

Parameters: $V_{ov} = V_{GS} - V_t$, $k_n = \mu_n C_{ox} \frac{W}{L}$

	Source	Drain	I_D
Cutoff (open switch)	$V_{GS} \leq V_t$		0
Triode (V. ctr. R)	$V_{GS} > V_t$	$V_{GD} > V_t, V_{DS} < V_{ov}$	$k_n [V_{ov} V_{DS} - \frac{V_{DS}^2}{2}]$
Saturation (V. ctr. I_S)	$V_{GS} > V_t$	$V_{GD} \leq V_t, V_{DS} \geq V_{ov}$	$\frac{1}{2} k_n V_{ov}^2 [1 + \lambda V_{DS}]$



BJTs

Structure: P, N, P

Equation: $i_C = I_S e^{V_{BE}/V_T} [1 + \frac{V_{CE}}{V_A}]$

Parameters: $\alpha = \frac{\beta}{\beta+1}$, $\beta = \frac{\alpha}{1-\alpha}$

Regions: Cutoff, Active, Saturation

Assume: $V_{BE} = 0.7\text{V}$, $V_{BC} < 0.4\text{V}$

Verify: $V_{BE} < 0.4\text{V}$, $V_{BC} < 0.4\text{V}$

Transistor Small Signal Models

MOSFET in saturation, BJT in active

MOSFET ($V_{GS} < 2V_{ov}$): $g_m = \frac{I_C}{V_T}$, $r_o = \frac{V_A}{I_D}$

BJT ($V_{BE} < V_T$): $r_e = \frac{V_T}{I_E}$, $r_\pi = \frac{V_T}{I_B}$

Transistor Amplifiers: [gate/base can never be output] [drain/collector can never be input] [CD: source flow] [CE: emitter flow]

CS/CE

Diagram: $V_i \rightarrow V_O$

Equation: $\frac{V_O}{V_i} = -\frac{R_D}{1/g_m} = -g_m R_D$

Input resistance: $R_{in} = r_\pi + (\beta+1)r_e$

CS/CE w/ resistor

Diagram: $V_i \rightarrow V_O$

Equation: $\frac{V_O}{V_i} = -\frac{R_C}{r_e + R_E} = -\frac{\alpha R_C}{r_e + R_E}$

CD/CC (follower)

Diagram: $V_i \rightarrow V_O$

Equation: $\frac{V_O}{V_i} = \frac{R_E}{R_E + r_e} \approx 1$

CG/CB

Diagram: $V_i \rightarrow V_O$

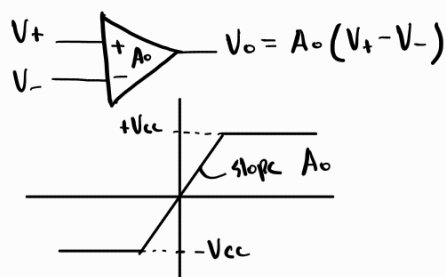
Equation: $\frac{V_O}{V_i} = \frac{R_D}{R_S \parallel 1/g_m} = g_m R_D$

Input/Output Resistance

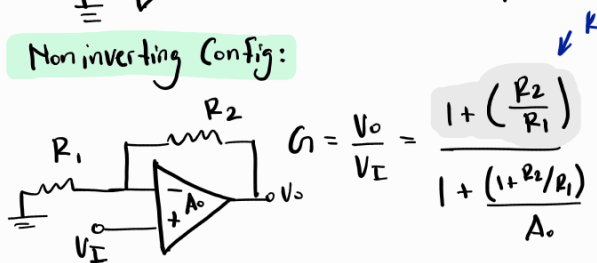
$R_{in} = r_\pi + (\beta+1)(r_e + R_E)$

$R_{out} = R_D \parallel \frac{1}{g_m}$

- 1) $i_+ = i_- = 0$ (opamp)
- 2) $V_- = V_+$ (negative feedback)



$$G = \frac{V_O}{V_I} = \frac{-\frac{R_2}{R_1}}{1 + \frac{(1+R_2/R_1)}{A_0}}$$



A circuit diagram of a voltage follower (buffer) configuration. It features an operational amplifier (op-amp) represented by a triangle. The non-inverting input, marked with a '+' sign, is connected to an input voltage V_I . The inverting input, marked with a '-' sign, is connected to the output of the op-amp, which is labeled V_O . A feedback loop is formed by a wire connecting the output V_O back to the inverting input. Below the output label, the equation $V_O = V_I$ is written, indicating that the output voltage is equal to the input voltage.

V_{test}



$V_o = A_o V_{test}$

A_o : op amp gain (no feedback) (device)





$$G_1: \frac{V_o}{V_I} \left(= -\frac{R_2}{R_1} \right) \text{ ex}$$

Diagram of an inverting summing amplifier circuit. The circuit consists of an operational amplifier (op-amp) configured with its non-inverting input (+) grounded. The inverting input (-) is connected to a summing junction where multiple input voltages $V_1, \dots, V_n$ are applied through resistors $R_1, \dots, R_n$. A feedback resistor R_F connects the output V_o back to the inverting input. The output voltage is given by the equation:

$$V_o = -R_F \left(\frac{V_1}{R_1} + \dots + \frac{V_n}{R_n} \right)$$

Subtractor

$$V_0 = \frac{R_2}{R_1} (V_2 - V_1)$$

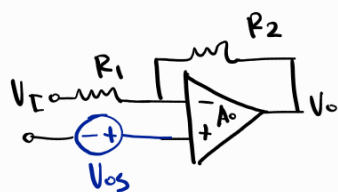
$R_{di} = 2R_1$

Integrator

$$V_O = -\frac{1}{RC} \int V_I dt$$

$V_O = -RC \frac{d}{dt} V_I$

Offset Voltage



can compensate by adding capacitor for AC signals

compensate by adding

$$R_3 = R_1 \parallel R_2$$

- 1) V_{omax} : max output voltage
- 2) I_{omax} : max output current
- 3) Slew rate: max rate of change of the output voltage

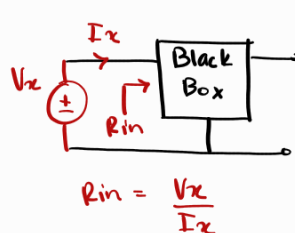
$$f_M = \frac{SR}{2\pi V_{\text{omax}}}$$

In phase wave: $P_{IV} = V_S$
 Half wave: $P_{IV} = 2V_S - V_D$
 Out of phase: $P_{IV} = V_S - V_D$
 $x(t_s) = x(\omega t_s) + \int x(t_s') - x(t_s) \left[e^{-(t-t_s) / \tau} \right] dt_s'$

$$\frac{I_1}{I_2} = \frac{(w/L)_1}{(w/L)_2} \quad \frac{I_1}{I_2} = \frac{A_1}{A_2}$$

$$\frac{I_1}{I_2} = \frac{A_1}{A_2}$$

$$P_{avg} = \frac{1}{2} V_{pk} \cdot I_{pk} = V_{rms} \cdot I_{rms} \quad \text{where } V_{rms} = \frac{1}{\sqrt{2}} V_{pk}, I_{rms} = \frac{1}{\sqrt{2}} I_{pk}$$



A circuit diagram showing a 'Black Box' connected to a voltage source V_x . The current flowing out of the positive terminal of the source is labeled I_x . The output resistance is labeled R_{out} .

$$R_{out} = \frac{V_x}{I_x}$$

If there is a resistor attached to the source, use T-model. Else use pi-model.

CS:	Q_{in}	A_{in}	P_0
CS,r:	∞	$-g_m P_D$	P_D
CS,r:	∞	$-\frac{g_m P_D}{1+g_m P_S}$	P_D
CA:	$\frac{1}{g_m}$	$g_m P_D$	P_D
CD,f:	∞	1	$\frac{1}{g_m}$
CE:	$(P_{in})/e$	$-g_m P_C$	P_C
CE,r:	$(P_{in})/(e+P_C)$	$-\frac{g_m P_C}{1+g_m P_C}$	P_C
CB:	e	$g_m P_C$	P_C
CC,f:	$(P_{in})/(e+P_C)$	1	e
	A_V	G_V	
CS:	$-g_m (P_{in} \ P_L)$	A_V	
CS,r:	$-\frac{g_m (P_{in} \ P_L)}{1+g_m P_S}$		
CA:	$g_m (P_{in} \ P_L)$		
CD,f:	$\frac{P_L}{P_L + 1/g_m}$		
CE:	$-g_m (P_C \ P_L)$		
CE,r:	$-\frac{g_m (P_C \ P_L)}{1+g_m P_C}$		
CB:	$g_m (P_C \ P_L)$		
CC,f:	$\frac{P_L}{P_L + e}$		